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October 1993 Revised April 2005

74LVX374

Low Voltage Octal D-Type Flip-Flop with 3-STATE Outputs

General Description

The LVX374 is a high-speed, low-power octal D-type flipflop featuring separate D-type inputs for each flip-flop and 3-STATE outputs for bus-oriented applications. A buffered Clock (CP) and Output Enable $(\overline{\text{OE}})$ are common to all flipflops. The inputs tolerate up to 7V allowing interface of 5V systems to 3V systems.

Features

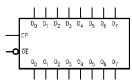
- Input voltage translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

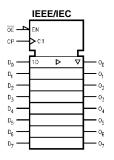
Ordering Code:

	Order Number	Package Number	Package Description
		M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
		M20D	Pb-Free 20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
	74LVX374MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code. Pb-Free package per JEDEC J-STD-020B.

Logic Symbols





Connection Diagram



Pin Descriptions

	Pin Names	Description
	D ₀ -D ₇	Data Inputs
	CP	Clock Pulse Input
	OE	3-STATE Output Enable Input
O ₀ -O ₇		3-STATE Outputs

Truth Table

	Outputs		
D _n	СР	ŌĒ	O _n
Н	~	L	Н
L	~	L	L
Х	Х	Н	Z

- H = HIGH Voltage Level L = LOW Voltage Level

- Z = High Impedance

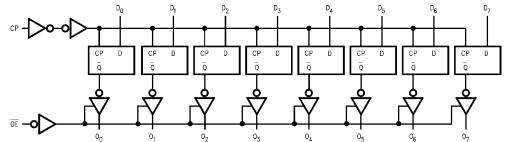
 Z = LOW-to-HIGH Transition

Functional Description

The LVX374 consists of eight edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP) transition.

With the Output Enable (OE) LOW, the contents of the eight flip-flops are available at the outputs. When the OE is HIGH, the outputs go to the high impedance state. Operation of the OE input does not affect the state of the flip-

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC}) -0.5V to +7.0V

DC Input Diode Current (I_{IK})

 $\begin{array}{lll} \mbox{V}_{\mbox{\scriptsize I}} = -0.5 \mbox{\scriptsize V} & -20 \mbox{ mA} \\ \mbox{\scriptsize DC Input Voltage (V}_{\mbox{\scriptsize I}}) & -0.5 \mbox{\scriptsize V} \mbox{\scriptsize to 7V} \end{array}$

DC Output Diode Current (I_{OK})

 V_{O} = -0.5V -20 mA V_{O} = V_{CC} +0.5V +20 mA

DC Output Voltage (V_O) -0.5V to $V_{CC} + 0.5V$

DC Output Source

or Sink Current (I_O) $\pm 25 \text{ mA}$

DC V_{CC} or Ground Current

 $\begin{array}{ll} (I_{CC} \ or \ I_{GND}) & \pm 75 \ mA \\ \\ \mbox{Storage Temperature} \ (T_{STG}) & -65 \ ^{\circ}\mbox{C} \ to +150 \ ^{\circ}\mbox{C} \end{array}$

Power Dissipation 180mW

Recommended Operating Conditions (Note 2)

 $\begin{array}{lll} \text{Supply Voltage (V}_{\text{CC}}) & 2.0 \text{V to } 3.6 \text{V} \\ \text{Input Voltage (V}_{\text{I}}) & 0 \text{V to } 5.5 \text{V} \\ \text{Output Voltage (V}_{\text{O}}) & 0 \text{V to } \text{V}_{\text{CC}} \end{array}$

Operating Temperature (T_A) -40° C to $+85^{\circ}$ C Input Rise and Fall Time ($\Delta t/\Delta V$) 0 ns/V to 100 ns/V

Input Rise and Fall Time (\Delta t \Delta v) 0 ns/v to 100 ns/v

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V _{CC}	T _A = +25°C			T _A = -40°	C to +85°C	Units	Conditions		
Syllibol	raiametei	•00	Min	Тур	Max	Min	Max	Units		niditions	
V _{IH}	HIGH Level	2.0	1.5			1.5					
	Input Voltage	3.0	2.0			2.0		V			
		3.6	2.4			2.4					
V _{IL}	LOW Level	2.0			0.5		0.5				
V _{IL} LOW Input ' VOH HIGH Output VOL LOW Output IOZ 3-STA Off-St I _{IN} Input i	Input Voltage	3.0			0.8		0.8	V			
		3.6			0.8		0.8				
V _{OH}	HIGH Level	2.0	1.9	2.0		1.9			$V_{IN} = V_{IH}$	$I_{OH} = -50\mu A$	
	Output Voltage	3.0	2.9	3.0		2.9		V	or V _{IL}	$I_{OH} = -50 \mu A$	
		3.0	2.58			2.48				$I_{OH} = -4mA$	
V _{OL}	LOW Level	2.0		0.0	0.1		0.1		$V_{IN} = V_{IH}$	$I_{OL} = 50 \mu A$	
	Output Voltage	3.0		0.0	0.1		0.1	V	or V _{IL}	$I_{OL} = 50 \mu A$	
		3.0			0.36		0.44			$I_{OL} = 4mA$	
loz	3-STATE Output	3.6			±0.25		±2.5		$V_{IN} = V_{IH} o$	r V _{IL}	
	Off-State Current							μΑ	V _{OUT} = V _{CC} or GND		
I _{IN}	Input Leakage Current	3.6			±0.1		±1.0	μА	$V_{IN}=5.5V$	or GND	
I _{CC}	Quiescent Supply Current	3.6			4.0		40.0	μΑ	$V_{IN} = V_{CC}$	or GND	

Noise Characteristics (Note 3)

Symbol	Parameter	V _{CC}	T _A = 25°C		Units	C _L (pF)	
C y 2 C.		(V)	Тур	Limit		- L (F-)	
V _{OLP}	Quiet Output Maximum Dynamic V _{OL}	3.3	0.5	0.8	V	50	
V _{OLV}	Quiet Output Minimum Dynamic V _{OL}	3.3	-0.5	-0.8	V	50	
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50	
V _{ILD}	Maximum LOW Level Dynamic Input Voltage			0.8	V	50	

Note 3: Input $t_r = t_f = 3 \text{ ns}$

AC Electrical Characteristics

Symbol	Parameter	v _{cc}		$T_A = +25^{\circ}C$	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units	Conditions	
Symbol	i didilictei	(V)	Min	Тур	Max	Min	Max	Units	Conditions
f _{MAX}	Maximum Clock	2.7	60	115		50			C _L = 15 pF
	Frequency		45	60		40		MHz	C _L = 50 pF
		3.3 ± 0.3	100	160		85		IVITIZ	C _L = 15 pF
			60	95		55			C _L = 50 pF
t _{PLH}	Propagation Delay Time	2.7		8.5	16.3	1.0	19.5		C _L = 15 pF
t _{PHL}	CP to O _n	1		11.0	19.8	1.0	23.0	ns	C _L = 50 pF
		3.3 ± 0.3		6.7	10.6	1.0	12.5	ns	C _L = 15 pF
		1		9.2	14.1	1.0	16.0		C _L = 50 pF
t _{PZL}	3-STATE Output	2.7		7.6	14.5	1.0	17.5		$C_L = 15 \text{ pF}, R_L = 1 \text{ k}\Omega$
t _{PZH}	Enable Time			10.1	18.0	1.0	21.0	ns	$C_L = 50 \text{ pF}, R_L = 1 \text{ k}\Omega$
		3.3 ± 0.3		5.9	9.3	1.0	11.0	ns	$C_L = 15 \text{ pF}, R_L = 1 \text{ k}\Omega$
		1		8.4	12.8	1.0	14.5		$C_L = 50 \text{ pF}, R_L = 1 \text{ k}\Omega$
t _{PLZ}	3-STATE Output	2.7		11.5	18.5	1.0	22.0	ns	$C_L = 50 \text{ pF}, R_L = 1 \text{ k}\Omega$
t_{PHZ}	Disable Time	3.3 ± 0.3		9.6	13.2	1.0	15.0	115	$C_L = 50 \text{ pF}, R_L = 1 \text{ k}\Omega$
t _W	CP Pulse	2.7	7.5			8.0		ns	
	Width	3.3 ± 0.3	5.0			5.5		115	
t _S	Setup Time	2.7	6.5			6.5		ns	
	D _n to CP	3.3 ± 0.3	4.5			4.5		115	
t _H	Hold Time	2.7	2.0			2.0			
	D _n to CP	3.3 ± 0.3	2.0			2.0		ns	
t _{OSLH}	Output to Output	2.7			1.5		1.5	ns	C _L = 50 pF
toshl	Skew (Note 4)	3.3			1.5		1.5	115	

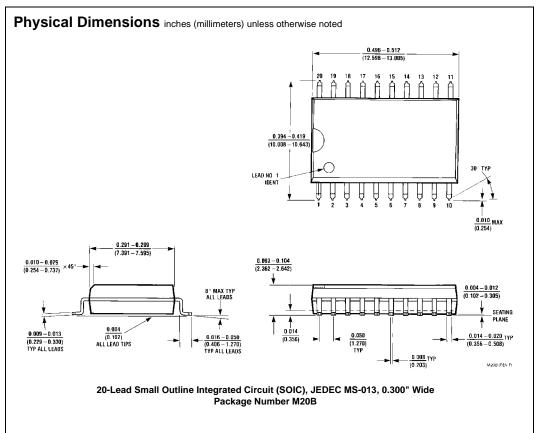
Note 4: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|$

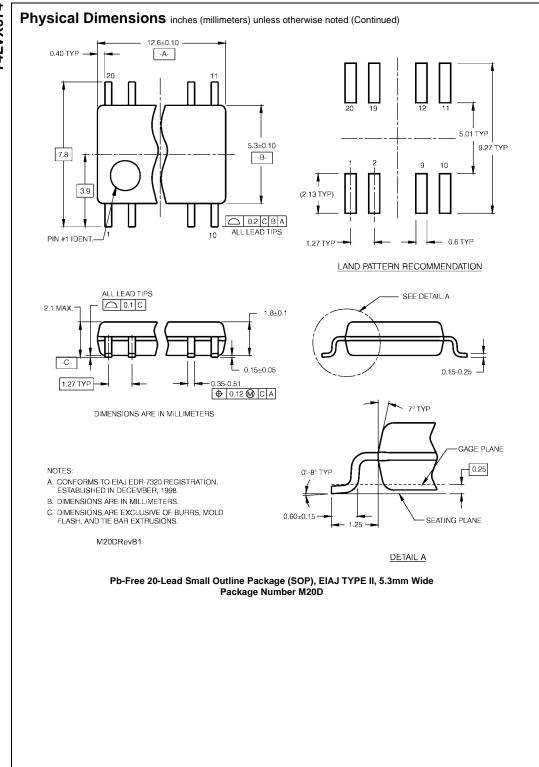
Capacitance

Symbol	Parameter	,	$T_A = +25^{\circ}C$		T _A = -40°C	Units	
Cymbol	T drameter		Тур	Max	Min		Max
C _{IN}	Input Capacitance		4	10		10	pF
C _{OUT}	Output Capacitance		6				pF
C _{PD}	Power Dissipation		32				pF
	Capacitance (Note 5)						

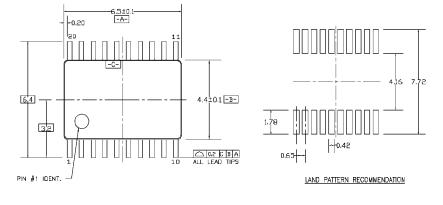
Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

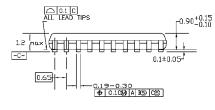
Average operating current can be obtained by the equation: $I_{CC(opr.)} = \frac{C_{PD} \times V_{CC} \times f_{IN} + I_{CC}}{8 \text{ (per F/F)}}$





Physical Dimensions inches (millimeters) unless otherwise noted (Continued)







SEE DETAIL A

DIMENSIONS ARE IN MILLIMETERS

NOTES:

- A. CONFORMS TO JEDEC REGISTRATION MD-153, VARIATION AC, REF NOTE 6, DATE 7/93.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.
- D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M. 1982.

RO.09min GAGE PLANE O.6±0.1 L.00 DETAIL A

MTC20REVD1

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC20

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